

MBRF2080CT

Technical Data Data Sheet N0827, Rev. A

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MBRF2080CT SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 High fragmency encapsion
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	80	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=116°C, rectangular wave form	10(Per Leg) 20(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	180	А

Electrical Characteristics:

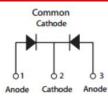
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@10A, Pulse, T _J = 25 °C	0.80	0.85	V
(Per Leg)*	V _{F2}	@10A, Pulse, T _J = 125 °C	0.68	0.75	V
Reverse Current at DC condition	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.05	1.0	mA
(Per Leg)*	I _{R2}	@V _R = rated V _R , T _J = 125 °C	10	150	mA
Junction Capacitance(Per Leg)	Ст	C_T @V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz		500	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body		-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, $T_A = 25 \degree$ C)	V _{ISO}	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	V
		Clip mounting, the epoxy body is inside the heatsink.	-	3500	
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

* Pulse width < 300 µs, duty cycle < 2%

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Circuit Diagram





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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ ext{ heta}JC}$	DC operation	2	°C/W
Approximate Weight	wt	-	2	g

Ratings and Characteristics Curves

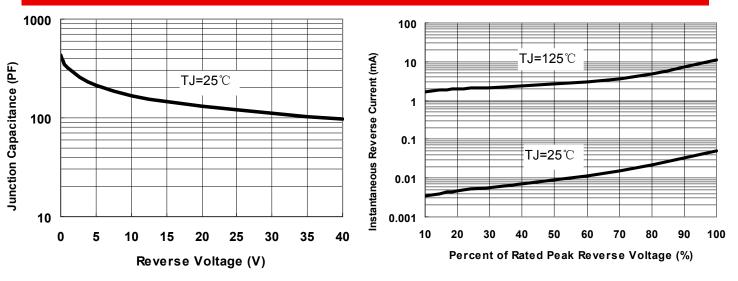




Fig.2-Typical Reverse Characteristics

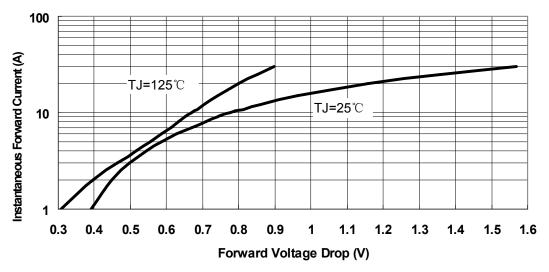


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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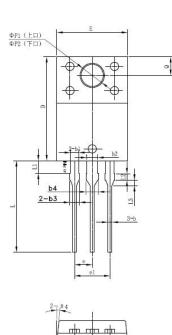


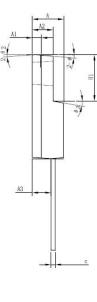
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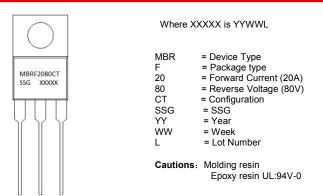
Mechanical Dimensions ITO-220AB





SYMBOL	Millimeters				
STWBOL	MIN.	TYP.	MAX.		
A	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
с	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
e		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
ΦΡ1(上口)	3.30	3.50	3.70		
ΦΡ2 (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

Marking Diagram



Ordering Information

32mm

Tube Specification

7mm

530mm

Device	Package	Shipping
MBRF2080CT	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification

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